

MRS SYMPOSIUM PROCEEDINGS

Volume 1536 • 2013 MRS Spring Meeting

Film Silicon Science and Technology

EDITORS

Paul Stradins

Akram Boukai

Friedhelm Finger

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Film Silicon Science and Technology

MATERIALS RESEARCH SOCIETY
SYMPOSIUM PROCEEDINGS VOLUME 1536

Film Silicon Science and Technology

Symposium held April 1–5, 2013, San Francisco, California U.S.A.

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Cambridge, New York, Melbourne, Madrid, Cape Town,
Singapore, São Paulo, Delhi, Mexico City

Cambridge University Press
32 Avenue of the Americas, New York, NY 10013-2473, USA

www.cambridge.org
Information on this title: www.cambridge.org/9781605115139

Materials Research Society
506 Keystone Drive, Warrendale, PA 15086
<http://www.mrs.org>

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First published 2013

CODEN: MRSPDH

ISBN: 978-1-60511-513-9 Hardback

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DEDICATION

The editors dedicate this volume,
Film Silicon Science and Technology,
to J. David Cohen and Stanford Ovshinsky.

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